## NSN 5961-01-518-4431

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-518-4431 **Inclosure Material:** Ceramic **Overall Length:** Between 50.42 millimeters and 51.69 millimeters **Overall Height:** Between 6.32 millimeters and 6.60 millimeters **Overall Width:** Between 13.59 millimeters and 13.89 millimeters **Function For Which Designed:** Rectifier **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 reverse voltage, average **Current Rating Per Characteristic:** 15.00 amperes drain current megahertz **Capacitance Rating In Picofarads:** 2000.0 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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